

UNISONIC TECHNOLOGIES CO., LTD

2N6116 **Preliminary SCR**

PROGRAMMABLE UNIJUNCTION TRANSISTOR

DESCRIPTION

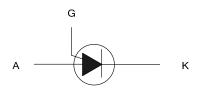
The UTC 2N6116 is a programmable unijunction transistor, it uses UTC's advanced technology to provide customers with low on-state voltage and high peak output voltage, etc.

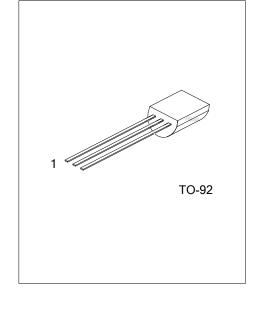
The UTC 2N6116 is suitable for thyristor-trigger, pulse, oscillator and timing circuits, etc.

FEATURES

- * High peak output voltage
- * Low on-state voltage
- * Low offset voltage
- * Low gate to anode leakage current

SYMBOL



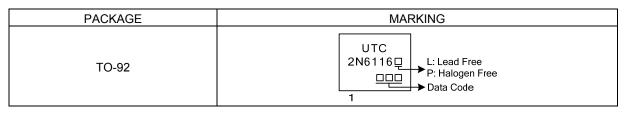


ORDERING INFORMATION

Ordering Number		Pin Assignment			Dooking	
Halogen Free	Package	1	2	3	Packing	
2N6116G-T92-B	TO-92	Α	G	K	Tape Box	
2N6116G-T92-K	TO-92	Α	G	K	Bulk	
r	Halogen Free 2N6116G-T92-B	Halogen Free Package 2N6116G-T92-B TO-92	Halogen Free 1 2N6116G-T92-B TO-92 A	Halogen Free Package 1 2 2N6116G-T92-B TO-92 A G	Halogen Free Package 1 2 3	

Note: Pin Assignment: A: Anode K: Cathode G: Gate 2N6116L-T92-B - (1)Packing Type (1) B: Tape Box, K: Bulk (2)Package Type (2) T92: TO-92 (3)Lead Free (3) L: Lead Free, G: Halogen Free

MARKING INFORMATION



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■ ABSOLUTE MAXIMUM RATINGS

PARAMETER		SYMBOL RATINGS		UNIT
Repetitive Peak Forward Current	100µs Pulse Width, 1% Duty Cycle	-	1	Α
	20µs Pulse Width, 1% Duty Cycle	I _{TRM}	2	Α
Non-Repetitive Peak Forward Current	10µs Pulse Width	I _{TSM}	5	Α
DC Forward Anode Current		Ι _Τ	200	mA
Derate Above 25°C			2	mA/°C
DC Gate Current		I_G	±20	mA
Gate to Cathode Forward Voltage		V_{GKF}	40	V
Gate to Cathode Reverse Voltage		V_{GKR}	5	V
Gate to Anode Reverse Voltage		V_{GAR}	40	V
Anode to Cathode Voltage		V_{AK}	±40	V
Forward Power Dissipation	T _A =25°C	P_F	250	mW
Derate Above 25°C		$1/\theta_{JA}$	2.5	mW/°C
Operating Junction Temperature		T_J	-65~+125	°C
Storage Junction Temperature		T_{STG}	-65~+200	°C

Notes: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ **ELECTRICAL CHARACTERISTICS** (T_A=25°C, unless otherwise noted.)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Offset Voltage	V _T	V_S =10V, R_G =1M Ω	0.2	0.70	1.6	V
		V_S =10V, R_G =10k Ω	0.2	0.35	0.6	V
Gate to Anode Leakage Current	1040	V _S =40V, T _A =25°C, Cathode Open		1	5	nA
		V _S =40V, T _A =75°C, Cathode Open		30	75	nA
Gate to Cathode Leakage Current	LOVO	V _S =40V, Anode to Cathode		5	50	nA
		Shorted		5		
Peak Current	I _P	V_S =10V, R_G =1M Ω		1.25	2	μΑ
		V_S =10V, R_G =10k Ω		4	5	μΑ
Valley Current	l _V	V_S =10V, R_G =1M Ω		18	50	μΑ
		V_S =10V, R_G =10k Ω	70	270		μΑ
Forward Voltage	V _F	I _F =50mA Peak		0.8	1.5	V
Peak Output Voltage	Vo	V _B =20V, C _C =0.2μF	6	16		V
Pulse Voltage Rise Time	t _R	V _B =20V, C _C =0.2μF		40	80	ns

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